

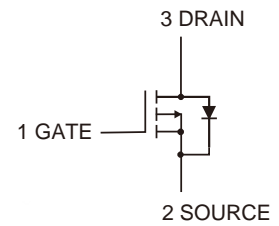
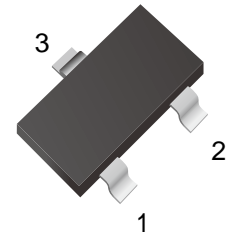
## P-Channel Mosfet

### Features

- Trench Technology Power MOSFET
- Low  $R_{DS(ON)}$
- Low Gate Charge
- Low Gate Resistance
- Lead free in comply with EU RoHS 2011/65/EU directives

### Mechanical Data

- Case: SOT-23
- Approx. Weight: 8.1mg



### Ordering Information

Part Number	Marking	Shipping	Reel
LTM3407PA-TR3	3407	3000PCS Tape&Reel	7 inchs
LTM3407PA-TR12	3407	12000PCS Tape&Reel	13 inchs

### Maximum Ratings ( $T_A=25$ unless otherwise noted )

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	-30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current, $T_A=25^\circ\text{C}$ (Note 1,5)	$I_D$	-4.1	A
Pulsed Drain Current(Note 2)	$I_{DM}$	-16	A
Power Dissipation, $T_A=25^\circ\text{C}$ (Note 4,5)	$P_D$	1.4	W
Thermal Resistance From Junction To Ambient(Note 5)	$R_{\theta JA}$	89	$^\circ\text{C/W}$
Junction And Storage Temperature Range	$T_j, T_{STG}$	-55 to +150	$^\circ\text{C}$

**Electrical Characteristics** ( $T_J=25^{\circ}\text{C}$  Unless Otherwise Noted)

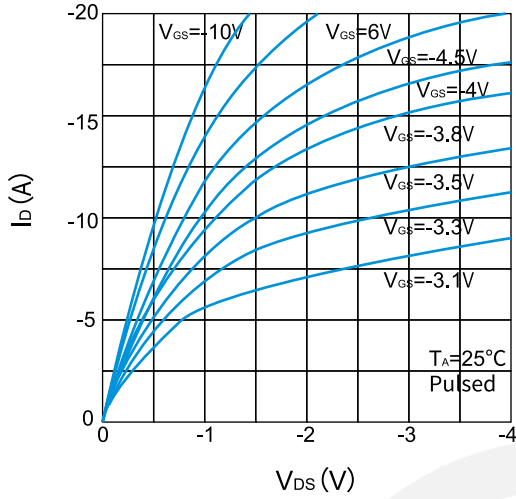
Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-30			V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=-24V, V_{GS}=0V$			-1	$\mu A$
Gate-Body Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$			$\pm 100$	nA
On Characteristics(Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-1	-1.6	-3	V
Drain-source On-resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-4.1A$		45	60	m $\Omega$
		$V_{GS}=-4.5V, I_D=-3A$		57	80	
Forward Transconductance	$g_{FS}$	$V_{DS}=-5V, I_D=-4A$	5			S
Dynamic Characteristics						
Input Capacitance	$C_{iss}$	$V_{DS}=-15V, V_{GS}=0V,$ $f=1\text{MHz}$		572		pF
Output Capacitance	$C_{oss}$			65		
Reverse Transfer Capacitance	$C_{rss}$			57		
Switching Characteristics						
Total Gate Charge	$Q_g$	$V_{DS}=-15V, V_{GS}=-10V,$ $I_D=-4.1A$		10		nC
Gate-source Charge	$Q_{gs}$			2		
Gate-drain Charge	$Q_{gd}$			3.4		
Turn-on Delay Time	$T_{d(on)}$	$V_{DD}=-15V, V_{GS}=-10V,$ $R_L=3.65\Omega, R_G=3\Omega$		8		nS
Turn-on Rise Time	$t_r$			6.2		
Turn-off Delay Time	$T_{d(off)}$			25		
Turn-off Fall Time	$t_f$			10		
Source-drain Diode Characteristics						
Diode Forward Voltage(Note 3)	$V_{SD}$	$V_{GS}=0V, I_S=-2A$			1.2	V

**Notes:**

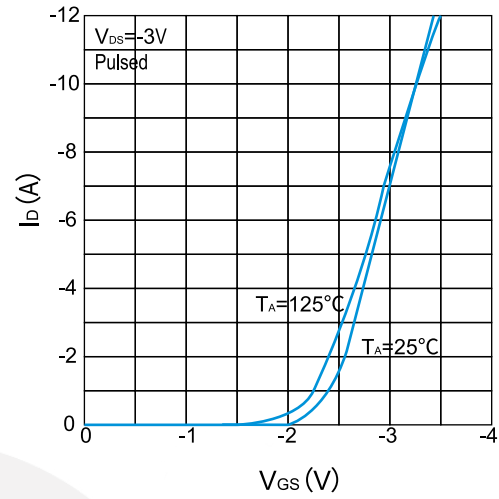
1. The Maximum Current Rating Is Limited By Package
2. Pulse Test: Pulse Width $\leq 10\mu S$ , Duty Cycle $\leq 1\%$
3. Pulse Test: Pulse Width $\leq 300\mu S$ , Duty Cycle $\leq 2\%$
4. The Power Dissipation  $P_D$  Is Limited By  $T_{J(MAX)}=150^{\circ}\text{C}$
5. Device Mounted On 1 In<sup>2</sup> FR-4 Board With 2oz. Copper, In A Still Air Environment With  $T_A=25^{\circ}\text{C}$

**Characteristics Curve**

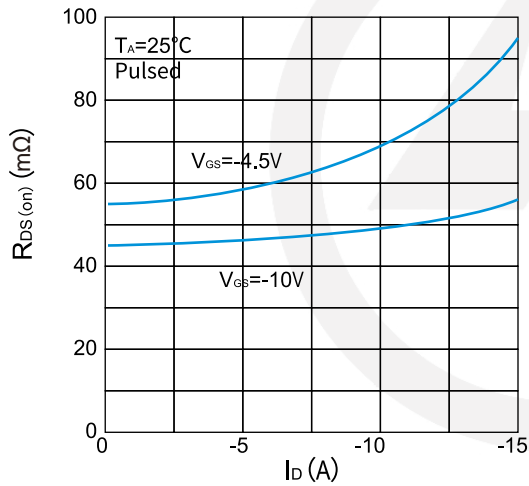
**Fig1.Output Characteristics**



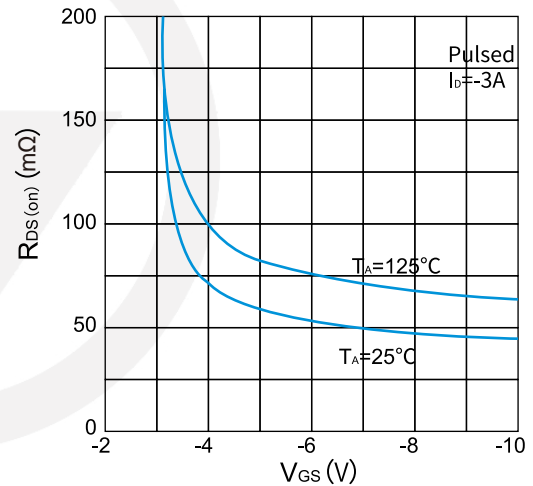
**Fig2.Transfer Characteristics**



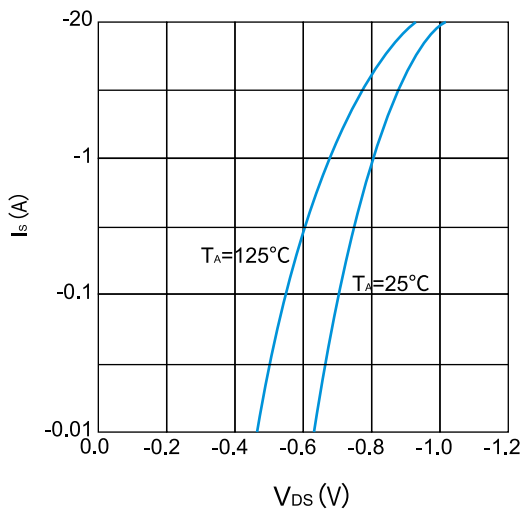
**Fig3.RDS(ON) VS Id**



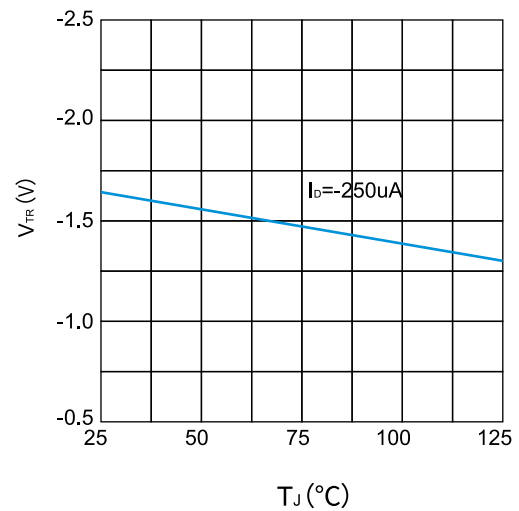
**Fig4.RDS(ON) VS Vgs**



**Fig5.Is vs VSD**

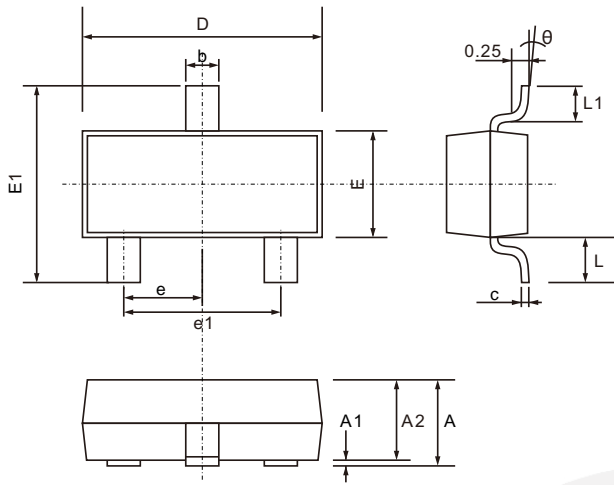


**Fig6.Threshold Voltage**



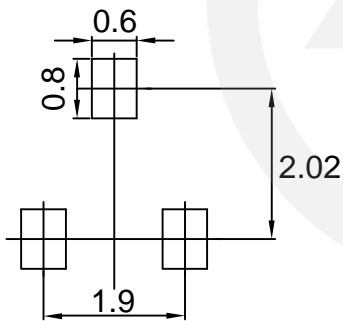
**SOT-23 Package Outline**

Unit: mm



SYMBOL	DIMENSIONS	
	MIN.	MAX.
A	0.900	1.200
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.200
D	2.700	3.100
E	1.200	1.400
E1	2.200	2.600
e	0.950 TYP.	
e1	1.750	2.050
L	0.550 TYP.	
L1	0.300	0.500
$\theta$	0°	8°

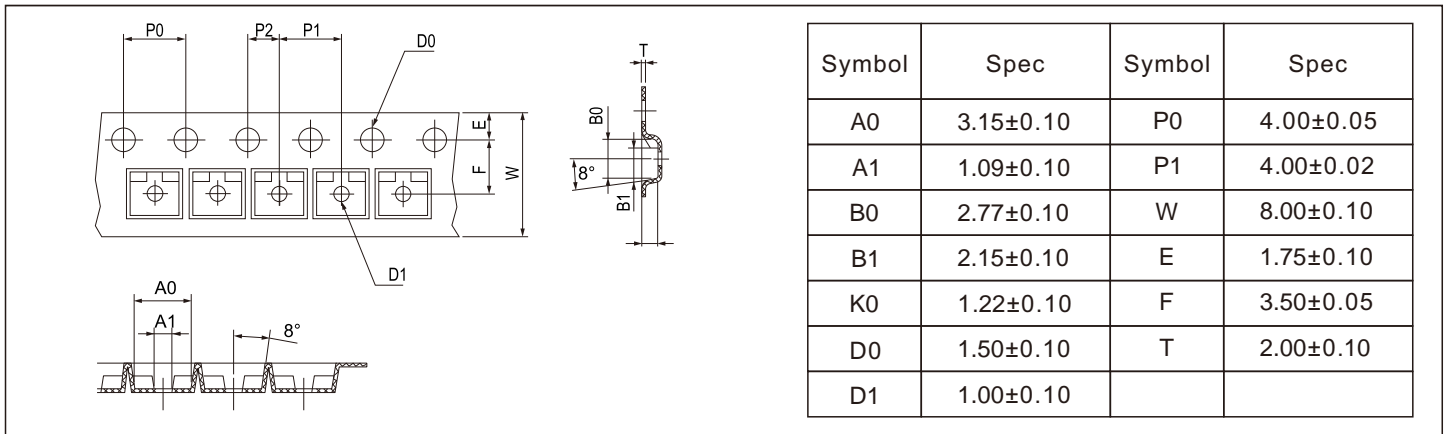
**SOT-23 Suggested Pad Layout**



- Note:
1. Controlling dimension: in millimeters.
  2. General tolerance:  $\pm 0.05\text{mm}$
  3. The pad layout is for reference purpose only.

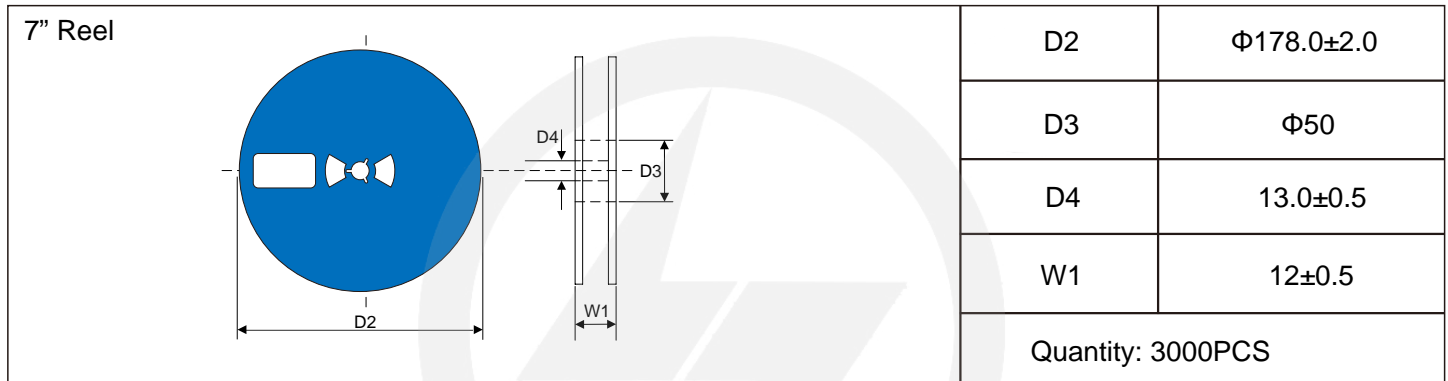
**Carrier Tape Dimensions**

Unit : mm



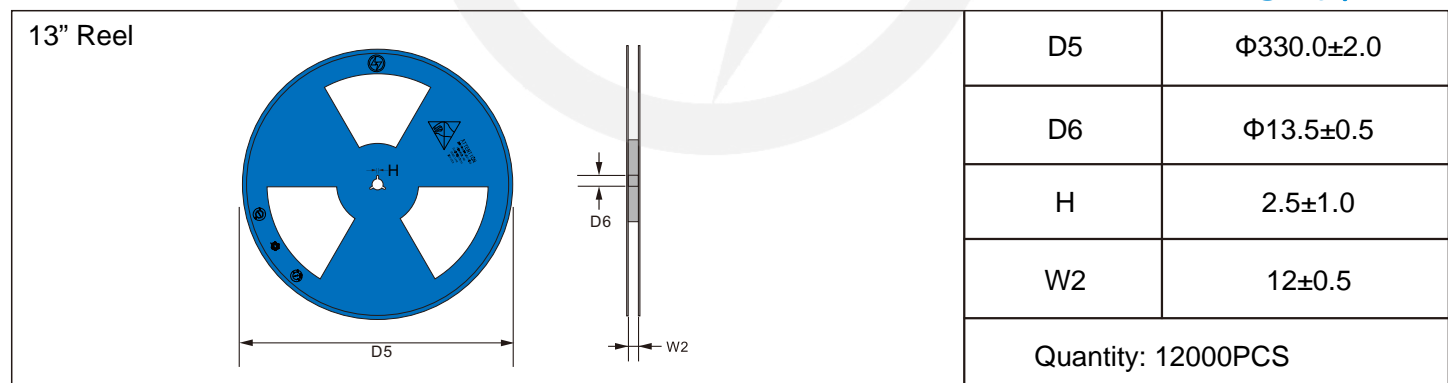
**Reel Dimensions**

Unit : mm

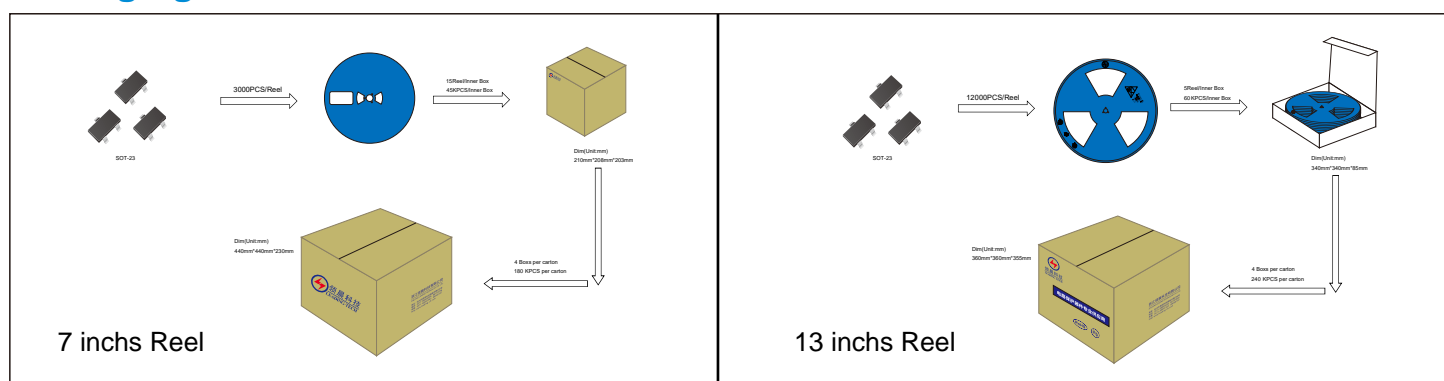


**Reel Dimensions**

Unit : mm

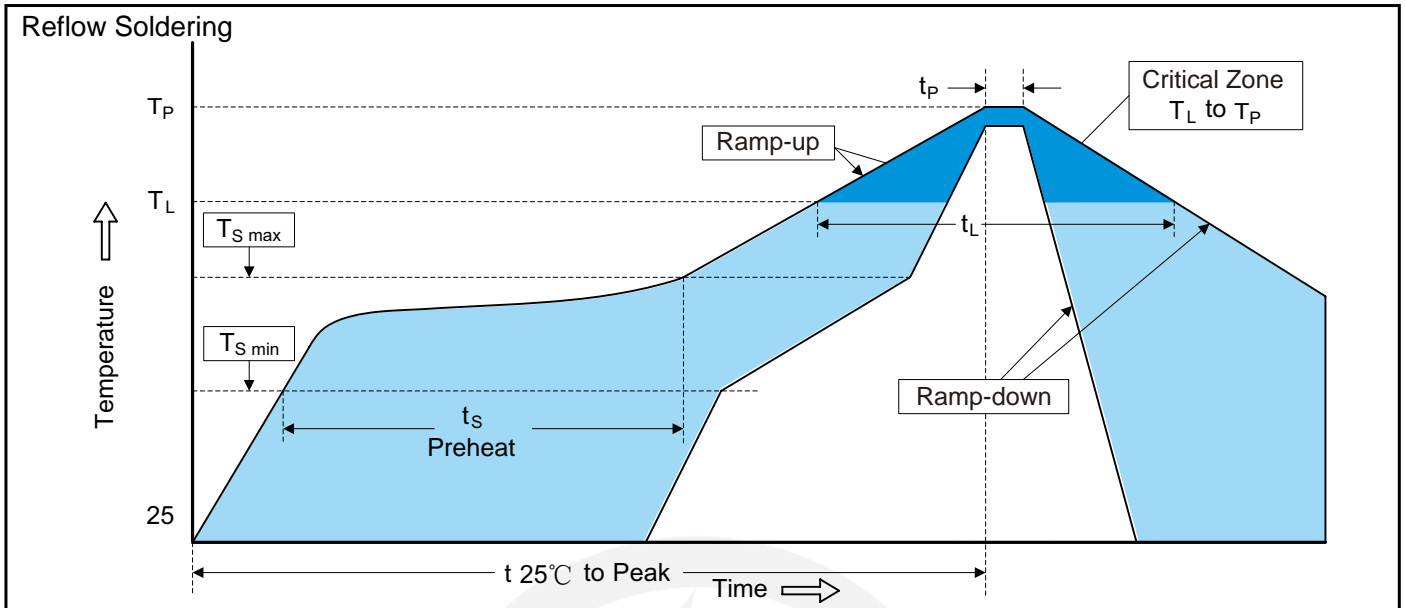


**Packaging**





Recommended Soldering Conditions



Recommended Conditions

Profile Feature	Pb-Free Assembly
Average ramp-up rate (T <sub>L</sub> to T <sub>P</sub> )	3°C/second max.
Preheat	
-Temperature Min (T <sub>S min</sub> )	150°C
-Temperature Max (T <sub>S max</sub> )	200°C
-Time (min to max) (t <sub>s</sub> )	60-180 seconds
T <sub>S max</sub> to T <sub>L</sub>	
-Ramp-up Rate	3°C/second max.
Time maintained above:	
-Temperature (T <sub>L</sub> )	217°C
-Time (t <sub>L</sub> )	60-150 seconds
Peak Temperature (T <sub>P</sub> )	260°C
Time within 5°C of actual Peak Temperature (t <sub>p</sub> )	20-40 seconds
Ramp-down Rate	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

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## Version Update Information

Series NO.	Enactment/Revision Date	Effective Date	Version	Revision Content	Revision Reason	Revision Person	Note
01	2024.05.18	2024.05.18	3.0	New file	/	Ding	
02	2025.06.17	2025.06.17	3.1	Update packaging information	/	Ding	
03	2026.03.05	2026.03.05	3.2	Package outline E1(max)=2.6mm	/	Ding	